Product data sheet

1. General description

NPN low V_{CEsat} transistor in a SOT223 plastic package. PNP complement: PBSS5350Z.

2. Features and benefits

- · Low collector-emitter saturation voltage
- High collector current capability: I_C and I_{CM}
- High collector current gain (h_{FE}) at high I_C
- · Higher efficiency leading to less heat generation
- · Reduced PCB area requirements compared to DPAK.
- AEC-Q101 qualified

3. Applications

- Power management
 - DC/DC converters
 - Supply line switching
 - Battery charger
 - Linear voltage regulation (LDO).
- Peripheral drivers
 - Driver in low supply voltage applications, e.g. lamps, LEDs
 - · Inductive load driver, e.g. relays, buzzers, motors.

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	50	V
I _C	collector current			-	-	3	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	-	5	Α
h _{FE}	DC current gain	V _{CE} = 2 V; I _C = 500 mA; T _{amb} = 25 °C	[1]	200	-	-	
R _{CEsat}	collector-emitter saturation resistance	I _C = 2 A; I _B = 200 mA; T _{amb} = 25 °C	[1]	-	110	145	mΩ

[1] Pulse test: $t_p \le 300 \ \mu s$; $\delta \le 0.02$



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	4	С
2	С	collector		В
3	E	emitter		- Th
4	С	collector		E sym123

6. Ordering information

Table 3. Ordering information

Type number	Package	ackage					
	Name	Description	Version				
PBSS4350Z	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223				

7. Marking

Table 4. Marking codes

Type number	Marking code
PBSS4350Z	PB4350

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8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter		-	60	V
V _{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	6	V
I _C	collector current			-	3	Α
I _{CM}	peak collector current	single pulse; t _p ≤ 1 ms		-	5	Α
I _{BM}	peak base current			-	1	Α
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	1.35	W
			[2]	-	2	W
T _j	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm 2 . Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm 2 .

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
uig a)	thermal resistance in free air	in free air	[1]	-	-	92	K/W
	from junction to ambient		[2]	-	-	62.5	K/W

Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm^2 . Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 6 cm^2 .

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V _{CB} = 50 V; I _E = 0 A; T _{amb} = 25 °C		-	-	100	nA
	current	V _{CB} = 50 V; I _E = 0 A; T _j = 150 °C		-	-	50	μΑ
I _{EBO}	emitter-base cut-off current	V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 2 V; I _C = 500 mA; T _{amb} = 25 °C	[1]	200	-	-	
		V _{CE} = 2 V; I _C = 1 A; T _{amb} = 25 °C	[1]	200	-	-	
		V _{CE} = 2 V; I _C = 2 A; T _{amb} = 25 °C	[1]	100	-	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = 500 mA; I_B = 50 mA; T_{amb} = 25 °C	[1]	-	-	90	mV
		I _C = 1 A; I _B = 50 mA; T _{amb} = 25 °C	[1]	-	-	170	mV
		I _C = 2 A; I _B = 200 mA; T _{amb} = 25 °C	[1]	-	-	290	mV
R _{CEsat}	collector-emitter saturation resistance		[1]	-	110	145	mΩ
V _{BEsat}	base-emitter saturation voltage		[1]	-	-	1.2	V
V_{BEon}	base-emitter turn-on voltage	V _{CE} = 2 V; I _C = 1 A; T _{amb} = 25 °C	[1]	-	-	1.1	V
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 100 mA; f = 100 MHz; T_{amb} = 25 °C		100	-	-	MHz
C _c	collector capacitance	V _{CB} = 10 V; I _E = 0 A; i _e = 0 A; f = 1 MHz; T _{amb} = 25 °C		-	-	30	pF

^[1] Pulse test: $t_p \le 300 \ \mu s; \ \delta \le 0.02$

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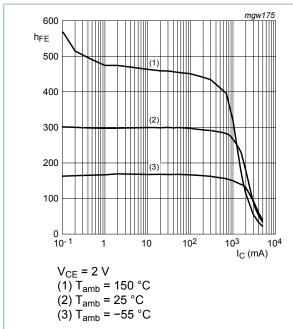


Fig. 1. DC current gain; typical values

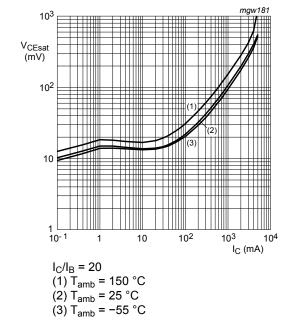


Fig. 3. Collector-emitter saturation as a function of collector current; typical values.

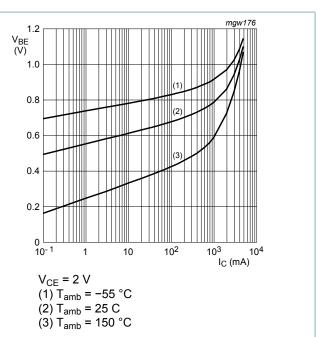


Fig. 2. Base-emitter voltage as a function of collectorcurrent; typical values

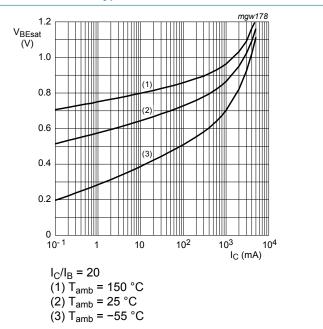


Fig. 4. Base-emitter saturation voltage as a function of collector current; typical values

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1.6

V_{CE} (V)

(6)

(7)

(8)

(9)

(10)

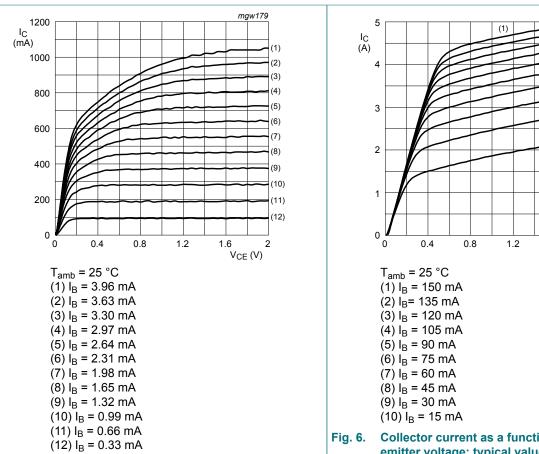
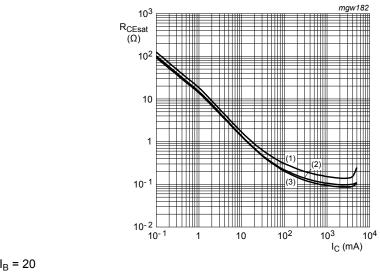


Fig. 5. Collector current as a function of collectoremitter voltage; typical values





 $I_C/I_B = 20$ (1) $T_{amb} = 150 \, ^{\circ}C$

(2) T_{amb} = 25 °C

(3) $T_{amb} = -55 \, ^{\circ}C$

Fig. 7. Collector-emitter equivalent on-resistance as a function of collector current; typical values

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11. Package outline

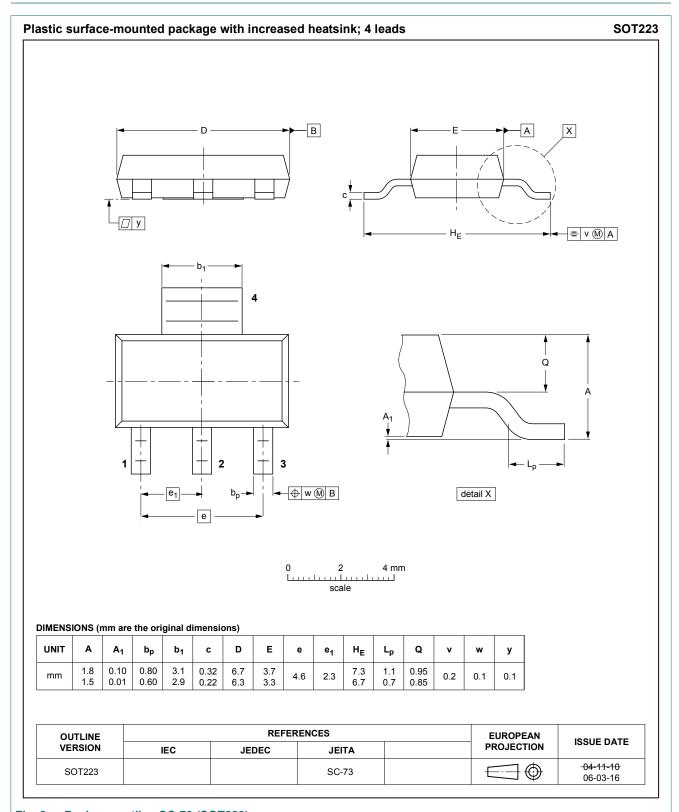
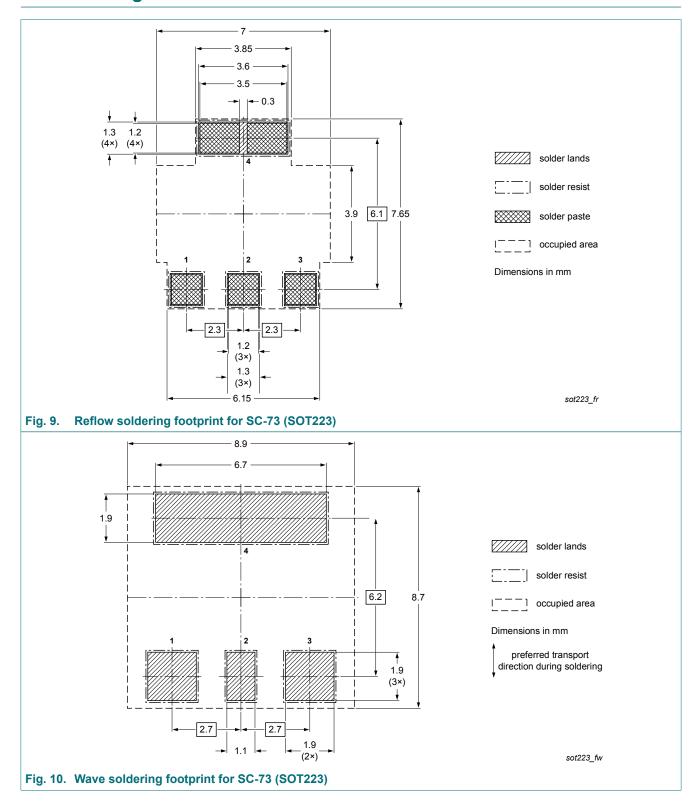


Fig. 8. Package outline SC-73 (SOT223)

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12. Soldering



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13. Revision history

Table 8. Revision history

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Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS4350Z v.3	20180626	Product data sheet	-	PBSS4350Z v.2
Modifications:	Nexperia.	7 corrected this data sheet has been redeave been adapted to the new control of the new c		
PBSS4350Z v.2	20030513	Product data sheet	-	PBSS4350Z v.1
PBSS4350Z v.1	20030120	Product data sheet	-	-

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14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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